

## **KSA916**

### **Audio Power Amplifier**

- Driver Stage Amplifier
- Complement to KSC2316



1. Emitter 2. Collector 3. Base

## **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	-120	V
$V_{CEO}$	Collector-Emitter Voltage	-120	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-800	mA
P <sub>C</sub>	Collector Power Dissipation	900	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -1 \text{mA } I_E = 0$	-120			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-120			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA, I <sub>C</sub> =0	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -120V, I <sub>E</sub> =0			-0.1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE}$ = -5V, $I_{C}$ = -10mA	60			
$h_{FE2}$		$V_{CE} = -5V, I_{C} = -100 \text{mA}$	80		240	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$			-1	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -5V, I <sub>C</sub> = -100mA		120		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1MHz			40	pF

## $h_{\text{FE}}$ Classification

Classification	0	Υ
h <sub>FE</sub>	80 ~ 160	120 ~ 240

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# **Typical Characteristics**

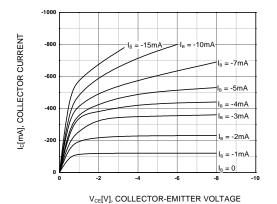


Figure 1. Static Characteristic

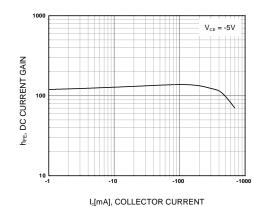


Figure 2. DC current Gain

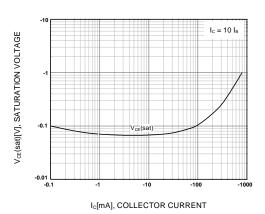


Figure 3. Collector-Emitter Saturation Voltage

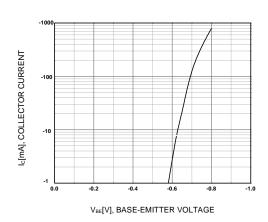


Figure 4. Base-Emitter On Voltage

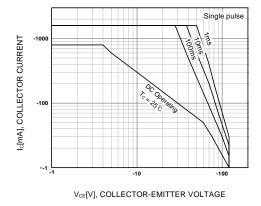


Figure 5. Safe Operating Area

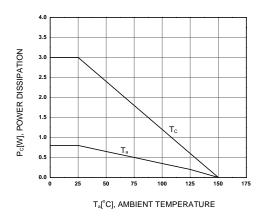
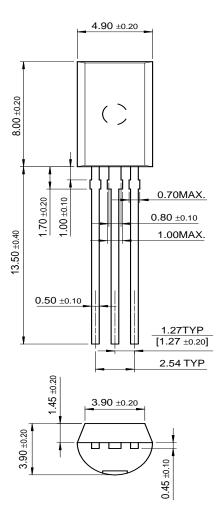


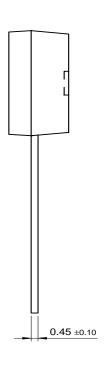
Figure 6. Power Derating

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# **Package Demensions**

# TO-92L





Dimensions in Millimeters

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